# 3. Ordering information

#### **Table 1. Ordering information**

Type number	Package							
	Temperature range	Name	Description	Version				
74LVC2T45DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads;	SOT765-1				
74LVCH2T45DC			body width 2.3 mm					
74LVC2T45GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads;	SOT833-1				
74LVCH2T45GT			8 terminals; body 1 × 1.95 × 0.5 mm					
74LVC2T45GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads;	SOT1089				
74LVCH2T45GF			8 terminals; body 1.35 × 1 × 0.5 mm					
74LVC2T45GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm	SOT902-2				
74LVC2T45GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads;	SOT1116				
74LVCH2T45GN			8 terminals; body 1.2 × 1.0 × 0.35 mm					
74LVC2T45GS	-40 °C to +125 °C	XSON8	XSON8 extremely thin small outline package; no leads;					
74LVCH2T45GS			8 terminals; body 1.35 × 1.0 × 0.35 mm					
74LVUNZ143US								

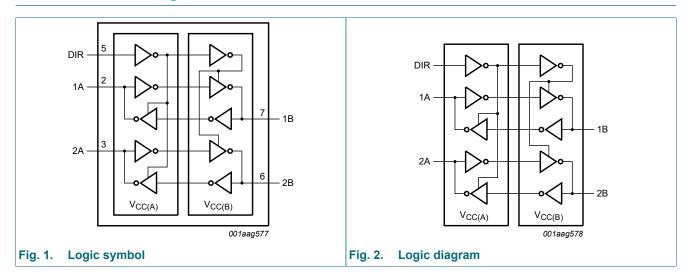
## 4. Marking

#### Table 2. Marking

Type number	Marking code [1]
74LVC2T45DC	V45
74LVCH2T45DC	X45
74LVC2T45GT	V45
74LVCH2T45GT	X45
74LVC2T45GF	V5
74LVCH2T45GF	X5
74LVC2T45GM	V45
74LVC2T45GN	V5
74LVCH2T45GN	X5
74LVC2T45GS	V5
74LVCH2T45GS	X5

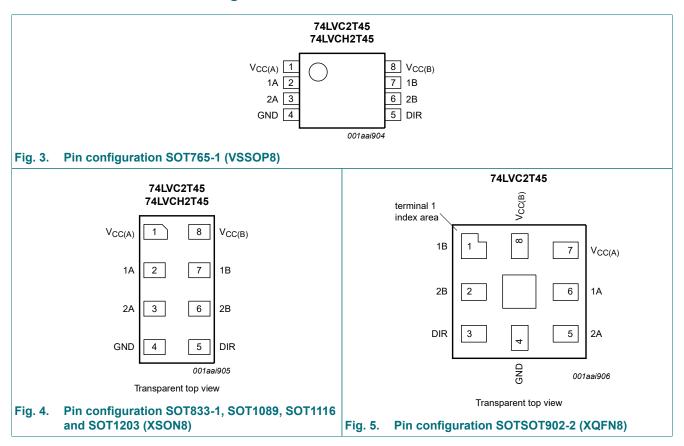
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

## 6.1. Pinning



## 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin		
	SOT765-1, SOT833-1, SOT1089, SOT1116 and SOT1203	SOT902-2		
V <sub>CC(A)</sub>	1	7	supply voltage A (port A and DIR)	
1A	2	6	data input or output	
2A	3	5	data input or output	
GND	4	4	ground (0 V)	
DIR	5	3	direction control	
2B	6	2	data input or output	
1B	7	1	data input or output	
V <sub>CC(B)</sub>	8	8	supply voltage B (port B)	

# 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care; \ Z = high-impedance \ OFF-state.$ 

Supply voltage	Input	Input/output [1]				
V <sub>CC(A)</sub> , V <sub>CC(B)</sub>	DIR	nA	nB			
1.2 V to 5.5 V	L	nA = nB	input			
1.2 V to 5.5 V	Н	input	nB = nA			
GND [2]	X	Z	Z			

<sup>[1]</sup> The input circuit of the data I/O is always active.

**Product data sheet** 

<sup>[2]</sup> When either  $V_{CC(A)}$  or  $V_{CC(B)}$  is at GND level, the device goes into suspend mode.

## 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC(A)</sub>	supply voltage A			-0.5	+6.5	V
V <sub>CC(B)</sub>	supply voltage B			-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
Vo	output voltage	Active mode	[1] [2] [3]	-0.5	V <sub>CCO</sub> + 0.5	V
		Suspend or 3-state mode	[1]	-0.5	+6.5	V
Io	output current	V <sub>O</sub> = 0 V to V <sub>CCO</sub>	[2]	-	±50	mA
I <sub>CC</sub>	supply current	I <sub>CC(A)</sub> or I <sub>CC(B)</sub>		-	100	mA
I <sub>GND</sub>	ground current			-100	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[4]	-	250	mW

- [1] The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed.
- [2] V<sub>CCO</sub> is the supply voltage associated with the output port.
- [3]  $V_{CCO}$  + 0.5 V should not exceed 6.5 V.
- [4] For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.
  - For SOT833-1 (XSON8) package:  $P_{tot}$  derates linearly with 3.1 mW/K above 68 °C.
  - For SOT1089 (XSON8) package:  $P_{tot}$  derates linearly with 4.0 mW/K above 88  $^{\circ}\text{C}.$
  - For SOT902-2 (XQFN8) packages:  $P_{tot}$  derates linearly with 4.1 mW/K above 89 °C.
  - For SOT1116 (XSON8) package:  $P_{tot}$  derates linearly with 4.2 mW/K above 90 °C.
  - For SOT1203 (XSON8) package: Ptot derates linearly with 3.6 mW/K above 81 °C.

# 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC(A)</sub>	supply voltage A		1.2	5.5	V
V <sub>CC(B)</sub>	supply voltage B		1.2	5.5	V
VI	input voltage		0	5.5	V
Vo	output voltage	Active mode [1]	0	V <sub>cco</sub>	V
		Suspend or 3-state mode	0	5.5	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CCI</sub> = 1.2 V [2]	-	20	ns/V
		V <sub>CCI</sub> = 1.4 V to 1.95 V	-	20	ns/V
		V <sub>CCI</sub> = 2.3 V to 2.7 V	-	20	ns/V
		V <sub>CCI</sub> = 3 V to 3.6 V	-	10	ns/V
		V <sub>CCI</sub> = 4.5 V to 5.5 V	-	5	ns/V

<sup>[1]</sup> V<sub>CCO</sub> is the supply voltage associated with the output port.

<sup>[2]</sup> V<sub>CCI</sub> is the supply voltage associated with the input port.

## 10. Static characteristics

## Table 7. Typical static characteristics at T<sub>amb</sub> = 25 °C

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $I_O = -3$ mA; $V_{CCO} = 1.2$ V	[1]	-	1.09	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $I_O = 3$ mA; $V_{CCO} = 1.2$ V	[1]	-	0.07	-	V
l <sub>l</sub>	input leakage current	DIR input; $V_1 = 0 \text{ V to } 5.5 \text{ V}$ ; $V_{CCI} = 1.2 \text{ V to } 5.5 \text{ V}$	[2]	-	-	±1	μA
I <sub>BHL</sub>	bus hold LOW current	A or B port; V <sub>I</sub> = 0.42 V; V <sub>CCI</sub> = 1.2 V	[2]	-	19	-	μΑ
I <sub>BHH</sub>	bus hold HIGH current	A or B port; V <sub>I</sub> = 0.78 V; V <sub>CCI</sub> = 1.2 V	[2]	-	-19	-	μΑ
I <sub>BHLO</sub>	bus hold LOW overdrive current	A or B port; V <sub>CCI</sub> = 1.2 V	[2] [3]	-	19	-	μA
I <sub>BHHO</sub>	bus hold HIGH overdrive current	A or B port; V <sub>CCI</sub> = 1.2 V	[2] [3]	-	-19	-	μΑ
l <sub>OZ</sub>	OFF-state output current	A or B port; $V_O = 0 \text{ V or } V_{CCO}$ ; $V_{CCO} = 1.2 \text{ V to } 5.5 \text{ V}$	[1]	-	-	±1	μA
I <sub>OFF</sub>	power-off leakage current	A port; $V_1$ or $V_0 = 0$ V to 5.5 V; $V_{CC(A)} = 0$ V; $V_{CC(B)} = 1.2$ V to 5.5 V		-	-	±1	μΑ
		B port; $V_1$ or $V_0 = 0$ V to 5.5 V; $V_{CC(B)} = 0$ V; $V_{CC(A)} = 1.2$ V to 5.5 V		-	-	±1	μA
Cı	input capacitance	DIR input; $V_1 = 0 \text{ V or } 3.3 \text{ V};$ $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$		-	2.2	-	pF
C <sub>I/O</sub>	input/output capacitance	A and B port; suspend mode; $V_O = 3.3 \text{ V}$ or 0 V; $V_{CC(A)} = V_{CC(B)} = 3.3 \text{ V}$		-	6.0	-	pF

<sup>[1]</sup>  $V_{CCO}$  is the supply voltage associated with the output port.

#### **Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	data input [1]					
	input voltage	V <sub>CCI</sub> = 1.2 V	0.8V <sub>CCI</sub>	-	0.8V <sub>CCI</sub>	-	V
		V <sub>CCI</sub> = 1.4 V to 1.95 V	0.65V <sub>CCI</sub>	-	0.65V <sub>CCI</sub>	-	V
		V <sub>CCI</sub> = 2.3 V to 2.7 V	1.7	-	1.7	-	V
		V <sub>CCI</sub> = 3.0 V to 3.6 V	2.0	-	2.0	-	V
		V <sub>CCI</sub> = 4.5 V to 5.5 V	0.7V <sub>CCI</sub>	-	0.7V <sub>CCI</sub>	-	V
		DIR input					
		V <sub>CCI</sub> = 1.2 V	0.8V <sub>CC(A)</sub>	-	0.8V <sub>CC(A)</sub>	-	V
		V <sub>CCI</sub> = 1.4 V to 1.95 V	0.65V <sub>CC(A)</sub>	-	0.65V <sub>CC(A)</sub>	-	V
		V <sub>CCI</sub> = 2.3 V to 2.7 V	1.7	-	1.7	-	V
		V <sub>CCI</sub> = 3.0 V to 3.6 V	2.0	-	2.0	-	V
		V <sub>CCI</sub> = 4.5 V to 5.5 V	0.7V <sub>CC(A)</sub>	-	0.7V <sub>CC(A)</sub>	-	V

<sup>[2]</sup> V<sub>CCI</sub> is the supply voltage associated with the data input port.

<sup>[3]</sup> To guarantee the node switches, an external driver must source/sink at least I<sub>BHLO</sub>/I<sub>BHHO</sub> when the input is in the range V<sub>IL</sub> to V<sub>IH</sub>.

Symbol	Parameter	Conditions		-40 °C to	o +85 °C	-40 °C to	Unit	
				Min	Max	Min	Max	
V <sub>IL</sub>	LOW-level input	data input [	1]					
	voltage	V <sub>CCI</sub> = 1.2 V		-	0.2V <sub>CCI</sub>	-	0.2V <sub>CCI</sub>	٧
		V <sub>CCI</sub> = 1.4 V to 1.95 V		-	0.35V <sub>CCI</sub>	-	0.35V <sub>CCI</sub>	٧
		V <sub>CCI</sub> = 2.3 V to 2.7 V		-	0.7	-	0.7	٧
		V <sub>CCI</sub> = 3.0 V to 3.6 V		-	0.8	-	0.8	٧
		V <sub>CCI</sub> = 4.5 V to 5.5 V		-	0.3V <sub>CCI</sub>	-	0.3V <sub>CCI</sub>	٧
		DIR input						
		V <sub>CCI</sub> = 1.2 V		-	0.2V <sub>CC(A)</sub>	-	0.2V <sub>CC(A)</sub>	٧
		V <sub>CCI</sub> = 1.4 V to 1.95 V		-	0.35V <sub>CC(A)</sub>	-	0.35V <sub>CC(A)</sub>	٧
		V <sub>CCI</sub> = 2.3 V to 2.7 V		-	0.7	-	0.7	V
		V <sub>CCI</sub> = 3.0 V to 3.6 V		-	0.8	-	0.8	V
		V <sub>CCI</sub> = 4.5 V to 5.5 V		-	0.3V <sub>CC(A)</sub>	-	0.3V <sub>CC(A)</sub>	٧
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$			, ,			
	output voltage	I <sub>O</sub> = -100 μA; [ V <sub>CCO</sub> = 1.2 V to 4.5 V	2] \	V <sub>CCO</sub> - 0.1	-	V <sub>CCO</sub> - 0.1	-	V
		I <sub>O</sub> = -6 mA; V <sub>CCO</sub> = 1.4 V		1.0	-	1.0	-	V
		I <sub>O</sub> = -8 mA; V <sub>CCO</sub> = 1.65 V		1.2	-	1.2	-	V
		I <sub>O</sub> = -12 mA; V <sub>CCO</sub> = 2.3 V		1.9	-	1.9	-	٧
		I <sub>O</sub> = -24 mA; V <sub>CCO</sub> = 3.0 V		2.4	-	2.4	-	V
		I <sub>O</sub> = -32 mA; V <sub>CCO</sub> = 4.5 V		3.8	-	3.8	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IL}$	2]					
		I <sub>O</sub> = 100 μA; V <sub>CCO</sub> = 1.2 V to 4.5 V		-	0.1	-	0.1	V
		I <sub>O</sub> = 6 mA; V <sub>CCO</sub> = 1.4 V		-	0.3	-	0.3	٧
		I <sub>O</sub> = 8 mA; V <sub>CCO</sub> = 1.65 V		-	0.45	-	0.45	٧
		I <sub>O</sub> = 12 mA; V <sub>CCO</sub> = 2.3 V		-	0.3	-	0.3	٧
		I <sub>O</sub> = 24 mA; V <sub>CCO</sub> = 3.0 V		-	0.55	-	0.55	V
		I <sub>O</sub> = 32 mA; V <sub>CCO</sub> = 4.5 V		-	0.55	-	0.55	V
I <sub>I</sub>	input leakage current	DIR input; V <sub>I</sub> = 0 V to 5.5 V; V <sub>CCI</sub> = 1.2 V to 5.5 V		-	±2	-	±10	μΑ
I <sub>BHL</sub>	bus hold LOW	A or B port [	1]					
	current	V <sub>I</sub> = 0.49 V; V <sub>CCI</sub> = 1.4 V		15	-	10	-	μA
		V <sub>I</sub> = 0.58 V; V <sub>CCI</sub> = 1.65 V		25	-	20	-	μA
		V <sub>I</sub> = 0.70 V; V <sub>CCI</sub> = 2.3 V		45	-	45	-	μA
		V <sub>I</sub> = 0.80 V; V <sub>CCI</sub> = 3.0 V		100	-	80	-	μA
		V <sub>I</sub> = 1.35 V; V <sub>CCI</sub> = 4.5 V		100	-	100	-	μA
I <sub>BHH</sub>	bus hold HIGH	A or B port	1]					
	current	V <sub>I</sub> = 0.91 V; V <sub>CCI</sub> = 1.4 V	+	-15	-	-10	-	μA
		V <sub>I</sub> = 1.07 V; V <sub>CCI</sub> = 1.65 V	+	-25	-	-20	-	μA
		V <sub>I</sub> = 1.60 V; V <sub>CCI</sub> = 2.3 V	+	-45	-	-45	-	μA
		V <sub>I</sub> = 2.00 V; V <sub>CCI</sub> = 3.0 V		-100	_	-80	-	μA
		V <sub>I</sub> = 3.15 V; V <sub>CCI</sub> = 4.5 V		-100	-	-100	-	μA

**Product data sheet** 

Symbol	Parameter	Conditions		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
				Min	Max	Min	Max	
I <sub>BHLO</sub>	bus hold LOW overdrive	A or B port	[1] [3]					
	current	V <sub>CCI</sub> = 1.6 V		125	-	125	-	μΑ
		V <sub>CCI</sub> = 1.95 V		200	-	200	-	μΑ
		V <sub>CCI</sub> = 2.7 V		300	-	300	-	μΑ
		V <sub>CCI</sub> = 3.6 V		500	-	500	-	μΑ
		V <sub>CCI</sub> = 5.5 V		900	-	900	-	μΑ
Івнно	bus hold HIGH overdrive	A or B port	[1] [3]					
	current	V <sub>CCI</sub> = 1.6 V		-125	-	-125	-	μΑ
		V <sub>CCI</sub> = 1.95 V		-200	-	-200	-	μΑ
		V <sub>CCI</sub> = 2.7 V		-300	-	-300	-	μΑ
		V <sub>CCI</sub> = 3.6 V		-500	-	-500	-	μΑ
		V <sub>CCI</sub> = 5.5 V		-900	-	-900	-	μA
I <sub>OZ</sub>	OFF-state output current	A or B port; $V_O = 0 \text{ V or } V_{CCO}$ ; $V_{CCO} = 1.2 \text{ V to } 5.5 \text{ V}$	[2]	-	±2	-	±10	μΑ
I <sub>OFF</sub>	power-off leakage current	A port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 5.5 V; V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 1.2 V to 5.5 V		-	±2	-	±10	μΑ
		B port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 5.5 V; V <sub>CC(B)</sub> = 0 V; V <sub>CC(A)</sub> = 1.2 V to 5.5 V		-	±2	-	±10	μΑ
I <sub>CC</sub>	supply current	A port; $V_I = 0 \text{ V or } V_{CCI}$ ; $I_O = 0 \text{ A}$	[1]					
		V <sub>CC(A)</sub> , V <sub>CC(B)</sub> = 1.2 V to 5.5 V		-	8	-	8	μΑ
		V <sub>CC(A)</sub> , V <sub>CC(B)</sub> = 1.65 V to 5.5 V		-	3	-	3	μA
		V <sub>CC(A)</sub> = 5.5 V; V <sub>CC(B)</sub> = 0 V		-	2	-	2	μΑ
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 5.5 \text{ V}$		-2	-	-2	-	μΑ
		B port; $V_I = 0 \text{ V or } V_{CCI}$ ; $I_O = 0 \text{ A}$						
		V <sub>CC(A)</sub> , V <sub>CC(B)</sub> = 1.2 V to 5.5 V		-	8	-	8	μΑ
		$V_{CC(A)}$ , $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		-	3	-	3	μΑ
		$V_{CC(B)} = 0 \text{ V}; V_{CC(A)} = 5.5 \text{ V}$		-2	-	-2	-	μΑ
		V <sub>CC(B)</sub> = 5.5 V; V <sub>CC(A)</sub> = 0 V		-	2	-	2	μΑ
		A plus B port $(I_{CC(A)} + I_{CC(B)})$ ; $I_O = 0$ A; $V_I = 0$ V or $V_{CCI}$						
		V <sub>CC(A)</sub> , V <sub>CC(B)</sub> = 1.2 V to 5.5 V		-	16	-	16	μΑ
		V <sub>CC(A)</sub> , V <sub>CC(B)</sub> = 1.65 V to 5.5 V		-	4	-	4	μΑ
ΔI <sub>CC</sub>	additional supply current	per input; V <sub>CC(A)</sub> , V <sub>CC(B)</sub> = 3.0 V to 5.5 V						
		A port; A port at $V_{CC(A)}$ - 0.6 V; DIR at $V_{CC(A)}$ ; B port = open	[4]	-	50	-	75	μΑ
		DIR input; DIR at V <sub>CC(A)</sub> - 0.6 V; A port at V <sub>CC(A)</sub> or GND; B port = open		-	50	-	75	μΑ
		B port; B port at V <sub>CC(B)</sub> - 0.6 V; DIR at GND; A port = open	[4]	-	50	-	75	μΑ

 $<sup>\</sup>ensuremath{V_{\text{CCI}}}$  is the supply voltage associated with the data input port.

<sup>[1]</sup> [2]

 $V_{CCO}$  is the supply voltage associated with the output port. To guarantee the node switches, an external driver must source/sink at least  $I_{BHLO}/I_{BHHO}$  when the input is in the range  $V_{IL}$  to  $V_{IH}$ . [3]

For non bus hold parts only (74LVC2T45).

# 11. Dynamic characteristics

Table 9. Typical dynamic characteristics at  $V_{CC(A)}$  = 1.2 V and  $T_{amb}$  = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8; for waveforms see Fig. 6 and Fig. 7.

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>						
			1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
t <sub>PLH</sub>	LOW to HIGH	A to B	10.6	8.1	7.0	5.8	5.3	5.1	ns
	propagation delay	B to A	10.6	9.5	9.0	8.5	8.3	8.2	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	10.1	7.1	6.0	5.3	5.2	5.4	ns
		B to A	10.1	8.6	8.1	7.8	7.6	7.6	ns
t <sub>PHZ</sub>	HIGH to OFF-state propagation delay	DIR to A	9.4	9.4	9.4	9.4	9.4	9.4	ns
		DIR to B	12.0	9.4	9.0	7.8	8.4	7.9	ns
t <sub>PLZ</sub>	LOW to OFF-state propagation delay	DIR to A	7.1	7.1	7.1	7.1	7.1	7.1	ns
		DIR to B	9.5	7.8	7.7	6.9	7.6	7.0	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A [1]	20.1	17.3	16.7	15.4	15.9	15.2	ns
	propagation delay	DIR to B [1]	17.7	15.2	14.1	12.9	12.4	12.2	ns
t <sub>PZL</sub>	OFF-state to LOW propagation delay	DIR to A [1]	22.1	18.0	17.1	15.6	16.0	15.5	ns
		DIR to B [1]	19.5	16.5	15.4	14.7	14.6	14.8	ns

<sup>[1]</sup>  $t_{PZH}$  and  $t_{PZL}$  are calculated values using the formula shown in <u>Section 13.4</u>.

Table 10. Typical dynamic characteristics at  $V_{CC(B)}$  = 1.2 V and  $T_{amb}$  = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8; for waveforms see Fig. 6 and Fig. 7.

Symbol	Parameter	Conditions			V <sub>C</sub>	C(A)			Unit
			1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	10.6	9.5	9.0	8.5	8.3	8.2	ns
		B to A	10.6	8.1	7.0	5.8	5.3	5.1	ns
t <sub>PHL</sub>	HIGH to LOW	A to B	10.1	8.6	8.1	7.8	7.6	7.6	ns
	propagation delay	B to A	10.1	7.1	6.0	5.3	5.2	5.4	ns
t <sub>PHZ</sub>	HIGH to OFF-state propagation delay	DIR to A	9.4	6.5	5.7	4.1	4.1	3.0	ns
		DIR to B	12.0	6.1	5.4	4.6	4.3	4.0	ns
t <sub>PLZ</sub>	LOW to OFF-state	DIR to A	7.1	4.9	4.5	3.2	3.4	2.5	ns
	propagation delay	DIR to B	9.5	7.3	6.6	5.9	5.7	5.6	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A	1] 20.1	15.4	13.6	11.7	11.0	10.7	ns
	propagation delay	DIR to B	1] 17.7	14.4	13.5	11.7	11.7	10.7	ns
t <sub>PZL</sub>	OFF-state to LOW	DIR to A	1] 22.1	13.2	11.4	9.9	9.5	9.4	ns
	propagation delay	DIR to B	1] 19.5	15.1	13.8	11.9	11.7	10.6	ns

<sup>[1]</sup> t<sub>PZH</sub> and t<sub>PZL</sub> are calculated values using the formula shown in <u>Section 13.4</u>.

Table 11. Typical power dissipation capacitance at  $V_{CC(A)} = V_{CC(B)}$  and  $T_{amb} = 25$  °C

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		V <sub>CC(A)</sub> ar	nd V <sub>CC(B)</sub>		Unit
			1.8 V	2.5 V	3.3 V	5.0 V	
C <sub>PD</sub>	power dissipation capacitance[1] [2]	A port: (direction A to B); B port: (direction B to A)	2	3	3	4	pF
		A port: (direction A to B); B port: (direction B to A)	15	16	16	18	pF

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

[2]  $f_i = 10$  MHz;  $V_I = GND$  to  $V_{CC}$ ;  $t_r = t_f = 1$  ns;  $C_L = 0$  pF;  $R_L = \infty \Omega$ .

#### Table 12. Dynamic characteristics for temperature range -40 °C to +85 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8; for waveforms see Fig. 6 and Fig. 7.

Symbol Parameter Conditions V <sub>CC(B)</sub>							Unit						
			1.5 V :	± 0.1 V	1.8 V ±	0.15 V	2.5 V :	± 0.2 V	3.3 V :	± 0.3 V	5.0 V ±	± 0.5 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> =	1.4 V to 1.6 V							•					
t <sub>PLH</sub>	LOW to HIGH	A to B	2.8	21.3	2.4	17.6	2.0	13.5	1.7	11.8	1.6	10.5	ns
	propagation delay	B to A	2.8	21.3	2.6	19.1	2.3	14.9	2.3	12.4	2.2	12.0	ns
t <sub>PHL</sub>	HIGH to LOW	A to B	2.6	19.3	2.2	15.3	1.8	11.8	1.7	10.9	1.7	10.8	ns
	propagation delay	B to A	2.6	19.3	2.4	17.3	2.3	13.2	2.2	11.3	2.3	11.0	ns
t <sub>PHZ</sub>	HIGH to OFF-state	DIR to A	3.0	18.7	3.0	18.7	3.0	18.7	3.0	18.7	3.0	18.7	ns
	propagation delay	DIR to B	3.5	24.8	3.5	23.6	3.0	11.0	3.3	11.3	2.8	10.3	ns
t <sub>PLZ</sub>	LOW to OFF-state	DIR to A	2.4	11.4	2.4	11.4	2.4	11.4	2.4	11.4	2.4	11.4	ns
	propagation delay	DIR to B	2.8	18.3	3.0	17.2	2.5	9.4	3.0	10.1	2.5	9.4	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A [1]	-	39.6	-	36.3	-	24.3	-	22.5	-	21.4	ns
	propagation delay	DIR to B [1]	-	32.7	-	29.0	-	24.9	-	23.2	-	21.9	ns
t <sub>PZL</sub>	OFF-state to LOW	DIR to A [1]	-	44.1	-	40.9	-	24.2	-	22.6	-	21.3	ns
	propagation delay	DIR to B [1]	-	38.0	-	34.0	-	30.5	-	29.6	-	29.5	ns

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>										Unit
			1.5 V	± 0.1 V	1.8 V ±	0.15 V	2.5 V	± 0.2 V	/ 3.3 V ± 0.3 V		5.0 V ± 0.5 V		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> =	1.65 V to 1.95 V					1				1	1		
t <sub>PLH</sub>	LOW to HIGH	A to B	2.6	19.1	2.2	17.7	2.2	9.3	1.7	7.2	1.4	6.8	ns
	propagation delay	B to A	2.4	17.6	2.2	17.7	2.3	16.0	2.1	15.5	1.9	15.1	ns
t <sub>PHL</sub>	HIGH to LOW	A to B	2.4	17.3	2.0	14.3	1.6	8.5	1.8	7.1	1.7	7.0	ns
	propagation delay	B to A	2.2	15.3	2.0	14.3	2.1	12.9	2.0	12.6	1.8	12.2	ns
t <sub>PHZ</sub>	HIGH to OFF-state	DIR to A	2.9	17.1	2.9	17.1	2.9	17.1	2.9	17.1	2.9	17.1	ns
	propagation delay	DIR to B	3.2	24.1	3.2	21.9	2.7	11.5	3.0	10.3	2.5	8.2	ns
t <sub>PLZ</sub>	LOW to OFF-state	DIR to A	2.4	10.5	2.4	10.5	2.4	10.5	2.4	10.5	2.4	10.5	ns
	propagation delay	DIR to B	2.5	17.6	2.6	16.0	2.2	9.2	2.7	8.4	2.4	7.1	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A [1]	-	35.2	-	33.7	-	25.2	-	23.9	-	22.2	ns
	propagation delay	DIR to B [1]	-	29.6	-	28.2	-	19.8	-	17.7	-	17.3	ns
t <sub>PZL</sub>	OFF-state to LOW	DIR to A [1]	-	39.4	-	36.2	-	24.4	-	22.9	-	20.4	ns
	propagation delay	DIR to B [1]	-	34.4	-	31.4	-	25.6	-	24.2	-	24.1	ns
V <sub>CC(A)</sub> =	2.3 V to 2.7 V												
t <sub>PLH</sub>	LOW to HIGH	A to B	2.3	17.9	2.3	16.0	1.5	8.5	1.3	6.2	1.1	4.8	ns
	propagation delay	B to A	2.0	13.5	2.2	9.3	1.5	8.5	1.4	8.0	1.0	7.5	ns
t <sub>PHL</sub>	HIGH to LOW	A to B	2.3	15.8	2.1	12.9	1.4	7.5	1.3	5.4	0.9	4.6	ns
	propagation delay	B to A	1.8	11.8	1.9	8.5	1.4	7.5	1.3	7.0	0.9	6.2	ns
$t_{PHZ}$	HIGH to OFF-state	DIR to A	2.1	8.1	2.1	8.1	2.1	8.1	2.1	8.1	2.1	8.1	ns
	propagation delay	DIR to B	3.0	22.5	3.0	21.4	2.5	11.0	2.8	9.3	2.3	6.9	ns
$t_{PLZ}$	LOW to OFF-state	DIR to A	1.7	5.8	1.7	5.8	1.7	5.8	1.7	5.8	1.7	5.8	ns
	propagation delay	DIR to B	2.3	14.6	2.5	13.2	2.0	9.0	2.5	8.4	1.8	5.8	ns
$t_{PZH}$	OFF-state to HIGH	DIR to A [1]	-	28.1	-	22.5	-	17.5	-	16.4	-	13.3	ns
	propagation delay	DIR to B [1]	-	23.7	-	21.8	-	14.3	-	12.0	-	10.6	ns
$t_{PZL}$	OFF-state to LOW	DIR to A [1]	-	34.3	-	29.9	-	18.5	-	16.3	-	13.1	ns
	propagation delay	DIR to B [1]	-	23.9	-	21.0	-	15.6	-	13.5	-	12.7	ns
$V_{CC(A)} =$	3.0 V to 3.6 V												
$t_{PLH}$	LOW to HIGH	A to B	2.3	17.1	2.1	15.5	1.4	8.0	8.0	5.6	0.7	4.4	ns
	propagation delay	B to A	1.7	11.8	1.7	7.2	1.3	6.2	0.7	5.6	0.6	5.4	ns
$t_{PHL}$	HIGH to LOW	A to B	2.2	15.6	2.0	12.6	1.3	7.0	0.8	5.0	0.7	4.0	ns
	propagation delay	B to A	1.7	10.9	1.8	7.1	1.3	5.4	8.0	5.0	0.7	4.5	ns
$t_{\text{PHZ}}$	HIGH to OFF-state	DIR to A	2.3	7.3	2.3	7.3	2.3	7.3	2.3	7.3	2.7	7.3	ns
	propagation delay	DIR to B	2.9	18.0	2.9	16.5	2.3	10.1	2.7	8.6	2.2	6.3	ns
$t_{PLZ}$	LOW to OFF-state	DIR to A	2.0	5.6	2.0	5.6	2.0	5.6	2.0	5.6	2.0	5.6	ns
	propagation delay	DIR to B	2.3	13.6	2.4	12.5	1.9	7.8	2.3	7.1	1.7	4.9	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A [1]	-	25.4	-	19.7	-	14.0	-	12.7	-	10.3	ns
	propagation delay	DIR to B [1]	-	22.7	-	21.1	-	13.6	-	11.2	-	10.0	ns
t <sub>PZL</sub>	OFF-state to LOW	DIR to A [1]	-	28.9	-	23.6	-	15.5	-	13.6	-	10.8	ns
	propagation delay	DIR to B [1]	-	22.9	-	19.9	-	14.3	-	12.3	-	11.3	ns

**Product data sheet** 

Symbol	Parameter	Conditions					Vcc	(B)					Unit
			1.5 V :	± 0.1 V	1.8 V ±	0.15 V	2.5 V :	± 0.2 V	3.3 V	± 0.3 V	5.0 V ±	0.5 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> =	4.5 V to 5.5 V		•	'	'	'				'			
t <sub>PLH</sub>	LOW to HIGH	A to B	2.2	16.6	1.9	15.1	1.0	7.5	0.7	5.4	0.5	3.9	ns
	propagation delay	B to A	1.6	10.5	1.4	6.8	1.0	4.8	0.7	4.4	0.5	3.9	ns
t <sub>PHL</sub>	HIGH to LOW	A to B	2.3	15.3	1.8	12.2	1.0	6.2	0.7	4.5	0.5	3.5	ns
	propagation delay	B to A	1.7	10.8	1.7	7.0	0.9	4.6	0.7	4.0	0.5	3.5	ns
t <sub>PHZ</sub>	HIGH to OFF-state	DIR to A	1.7	5.4	1.7	5.4	1.7	5.4	1.7	5.4	1.7	5.4	ns
	propagation delay	DIR to B	2.9	17.3	2.9	16.1	2.3	9.7	2.7	8.0	2.5	5.7	ns
t <sub>PLZ</sub>	LOW to OFF-state	DIR to A	1.4	3.7	1.4	3.7	1.3	3.7	1.0	3.7	0.9	3.7	ns
	propagation delay	DIR to B	2.3	13.1	2.4	12.1	1.9	7.4	2.3	7.0	1.8	4.5	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A [1]	-	23.6	-	18.9	-	12.2	-	11.4	-	8.4	ns
	propagation delay	DIR to B [1]	-	20.3	-	18.8	-	11.2	-	9.1	-	7.6	ns
t <sub>PZL</sub>	OFF-state to LOW	DIR to A [1]	-	28.1	-	23.1	-	14.3	-	12.0	-	9.2	ns
	propagation delay	DIR to B [1]	-	20.7	-	17.6	-	11.6	-	9.9	-	8.9	ns

<sup>[1]</sup>  $t_{PZH}$  and  $t_{PZL}$  are calculated values using the formula shown in Section 13.4.

Table 13. Dynamic characteristics for temperature range -40 °C to +125 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8; for waveforms see Fig. 6 and Fig. 7.

•		, •	, ,										
Symbol	Parameter	Conditions					Vcc	(B)					Unit
			1.5 V :	± 0.1 V	1.8 V ±	0.15 V	2.5 V :	± 0.2 V	3.3 V :	± 0.3 V	5.0 V :	± 0.5 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> =	1.4 V to 1.6 V												
t <sub>PLH</sub>	LOW to HIGH	A to B	2.5	23.5	2.1	19.4	1.8	14.9	1.5	13.0	1.4	11.6	ns
	propagation delay	B to A	2.5	23.5	2.3	21.1	2.0	16.4	2.0	13.7	1.9	13.2	ns
t <sub>PHL</sub>	HIGH to LOW	A to B	2.3	21.3	1.9	16.9	1.6	13.0	1.5	12.0	1.5	11.9	ns
	propagation delay	B to A	2.3	21.3	2.1	19.1	2.0	14.6	1.9	12.5	2.0	12.1	ns
t <sub>PHZ</sub>	HIGH to OFF-state	DIR to A	2.7	20.6	2.7	20.6	2.7	20.6	2.7	20.6	2.7	20.6	ns
	propagation delay	DIR to B	3.1	27.3	3.1	26.0	2.7	12.1	2.9	12.5	2.5	11.4	ns
t <sub>PLZ</sub>	LOW to OFF-state	DIR to A	2.1	12.6	2.1	12.6	2.1	12.6	2.1	12.6	2.1	12.6	ns
	propagation delay	DIR to B	2.5	20.2	2.7	19.0	2.2	10.4	2.7	11.2	2.2	10.4	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A [1]	-	43.7	-	40.1	-	26.8	-	24.9	-	23.6	ns
	propagation delay	DIR to B [1]	-	36.1	-	32.0	-	27.5	-	25.6	-	24.2	ns
t <sub>PZL</sub>	OFF-state to LOW	DIR to A [1]	-	48.6	-	45.1	-	26.7	-	25.0	-	23.5	ns
	propagation delay	DIR to B [1]	-	41.9	-	37.5	-	33.6	-	32.6	-	32.5	ns

**Product data sheet** 

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>										Unit
			1.5 V	± 0.1 V	1.8 V ±	£ 0.15 V	2.5 V	± 0.2 V	3.3 V	± 0.3 V	5.0 V :	± 0.5 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> =	1.65 V to 1.95 V	1				1				1		1	1
t <sub>PLH</sub>	LOW to HIGH	A to B	2.3	21.1	1.9	19.5	1.9	10.3	1.5	8.0	1.2	7.5	ns
	propagation delay	B to A	2.1	19.4	1.9	19.5	2.0	17.6	1.8	17.1	1.7	16.7	ns
t <sub>PHL</sub>	HIGH to LOW	A to B	2.1	19.1	1.8	15.8	1.4	9.4	1.6	7.9	1.5	7.7	ns
	propagation delay	B to A	1.9	16.9	1.8	15.8	1.8	14.2	1.8	13.9	1.6	13.5	ns
t <sub>PHZ</sub>	HIGH to OFF-state	DIR to A	2.6	18.9	2.6	18.9	2.6	18.9	2.6	18.9	2.6	18.9	ns
	propagation delay	DIR to B	2.8	26.6	2.8	24.1	2.4	12.7	2.7	11.4	2.2	9.1	ns
t <sub>PLZ</sub>	LOW to OFF-state	DIR to A	2.1	11.6	2.1	11.6	2.1	11.6	2.1	11.6	2.1	11.6	ns
	propagation delay	DIR to B	2.2	19.4	2.3	17.6	1.9	10.2	2.4	9.3	2.1	7.9	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A [1]	-	38.8	-	37.1	-	27.8	-	26.4	-	24.6	ns
	propagation delay	DIR to B [1]	-	32.7	-	31.1	-	21.9	-	19.6	-	19.1	ns
t <sub>PZL</sub>	OFF-state to LOW	DIR to A [1]	-	43.5	-	39.9	-	26.9	-	25.3	-	22.6	ns
	propagation delay	DIR to B [1]	-	38.0	-	34.7	-	28.3	-	26.8	-	26.6	ns
V <sub>CC(A)</sub> =	2.3 V to 2.7 V					•	•	·					
t <sub>PLH</sub>	LOW to HIGH	A to B	2.0	19.7	2.0	17.6	1.3	9.4	1.1	6.9	0.9	5.3	ns
	propagation delay	B to A	1.8	14.9	1.9	10.3	1.3	9.4	1.2	8.8	0.9	8.3	ns
t <sub>PHL</sub>	HIGH to LOW	A to B	2.0	17.4	1.8	14.2	1.2	8.3	1.1	6.0	0.8	5.1	ns
	propagation delay	B to A	1.6	13.0	1.7	9.4	1.2	8.3	1.1	7.7	0.8	6.9	ns
t <sub>PHZ</sub>	HIGH to OFF-state	DIR to A	1.8	9.0	1.8	9.0	1.8	9.0	1.8	9.0	1.8	9.0	ns
	propagation delay	DIR to B	2.7	24.8	2.7	23.6	2.2	12.1	2.5	10.3	2.0	7.6	ns
$t_{PLZ}$	LOW to OFF-state	DIR to A	1.5	6.4	1.5	6.4	1.5	6.4	1.5	6.4	1.5	6.4	ns
	propagation delay	DIR to B	2.0	16.1	2.2	14.6	1.8	9.9	2.2	9.3	1.6	6.4	ns
$t_{PZH}$	OFF-state to HIGH	DIR to A [1]	-	31.0	-	24.9	-	19.3	-	18.1	-	14.7	ns
	propagation delay	DIR to B [1]	-	26.1	-	24.0	-	15.8	-	13.3	-	11.7	ns
$t_{PZL}$	OFF-state to LOW	DIR to A [1]	-	37.8	-	33.0	-	20.4	-	18.0	-	14.5	ns
	propagation delay	DIR to B [1]	-	26.4	-	23.2	-	17.3	-	15.0	-	14.1	ns
$V_{CC(A)} =$	3.0 V to 3.6 V												
$t_{PLH}$	LOW to HIGH	A to B	2.0	18.9	1.8	17.1	1.2	8.8	0.7	6.2	0.6	4.9	ns
	propagation delay	B to A	1.5	13.0	1.5	8.0	1.1	6.9	0.6	6.2	0.5	6.0	ns
$t_{PHL}$	HIGH to LOW	A to B	1.9	17.2	1.8	13.9	1.1	7.7	0.7	5.5	0.6	4.4	ns
	propagation delay	B to A	1.5	12.0	1.6	7.9	1.1	6.0	0.7	5.5	0.6	5.0	ns
$t_{PHZ}$	HIGH to OFF-state	DIR to A	2.0	8.1	2.0	8.1	2.0	8.1	2.0	8.1	2.4	8.1	ns
	propagation delay	DIR to B	2.6	19.8	2.6	18.2	2.0	11.2	2.4	9.5	1.9	7.0	ns
$t_{PLZ}$	LOW to OFF-state	DIR to A	1.8	6.2	1.8	6.2	1.8	6.2	1.8	6.2	1.8	6.2	ns
	propagation delay	DIR to B	2.0	15.0	2.1	13.8	1.7	8.6	2.0	7.9	1.5	5.4	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A [1]	-	28.0	-	21.8	-	15.5	-	14.1	-	11.4	ns
<u> </u>	propagation delay	DIR to B [1]	-	25.1	-	23.3	-	15.0	-	12.4	-	11.1	ns
$t_{PZL}$	OFF-state to LOW	DIR to A [1]	-	31.8	-	26.1	-	17.2	-	15.0	-	12.0	ns
	propagation delay	DIR to B [1]	-	25.3	-	22.0	-	15.8	-	13.6	-	12.5	ns

**Product data sheet** 

Symbol	Parameter	Conditions					Vcc	(B)					Unit
			1.5 V :	± 0.1 V	1.8 V ±	0.15 V	2.5 V :	± 0.2 V	3.3 V :	± 0.3 V	5.0 V ±	± 0.5 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>CC(A)</sub> =	4.5 V to 5.5 V		'		'		'		ı				
t <sub>PLH</sub>	LOW to HIGH	A to B	1.9	18.3	1.7	16.7	0.9	8.3	0.6	6.0	0.4	4.3	ns
	propagation delay	B to A	1.4	11.6	1.2	7.5	0.9	5.3	0.6	4.9	0.4	4.3	ns
t <sub>PHL</sub>	HIGH to LOW	A to B	2.0	16.9	1.6	13.5	0.9	6.9	0.6	5.0	0.4	3.9	ns
	propagation delay	B to A	1.5	11.9	1.5	7.7	0.8	5.1	0.6	4.4	0.4	3.9	ns
t <sub>PHZ</sub>	HIGH to OFF-state	DIR to A	1.5	6.0	1.5	6.0	1.5	6.0	1.5	6.0	1.5	6.0	ns
	propagation delay	DIR to B	2.6	19.1	2.6	17.8	2.0	10.7	2.4	8.8	2.2	6.3	ns
t <sub>PLZ</sub>	LOW to OFF-state	DIR to A	1.2	4.1	1.2	4.1	1.1	4.1	0.9	4.1	8.0	4.1	ns
	propagation delay	DIR to B	2.0	14.5	2.1	13.4	1.7	8.2	2.0	7.7	1.6	5.0	ns
t <sub>PZH</sub>	OFF-state to HIGH	DIR to A [1]	-	26.1	-	20.9	-	13.5	-	12.6	-	9.3	ns
	propagation delay	DIR to B [1]	-	22.4	-	20.8	-	12.4	-	10.1	-	8.4	ns
t <sub>PZL</sub>	OFF-state to LOW	DIR to A [1]	-	31.0	-	25.5	-	15.8	-	13.2	-	10.2	ns
	propagation delay	DIR to B [1]	-	22.9	-	19.5	-	12.9	-	11.0	-	9.9	ns

<sup>[1]</sup>  $t_{PZH}$  and  $t_{PZL}$  are calculated values using the formula shown in <u>Section 13.4</u>.

#### 11.1. Waveforms and test circuit

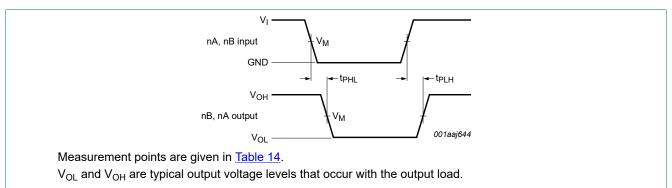
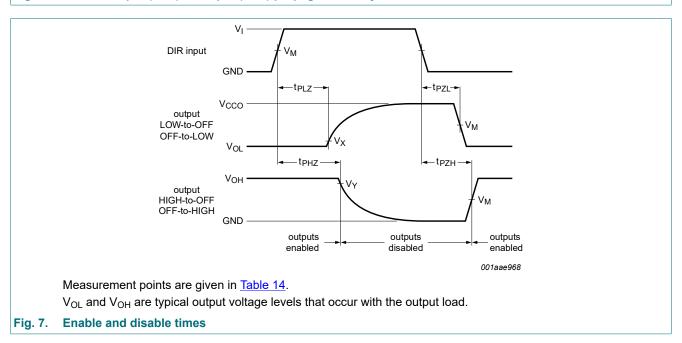


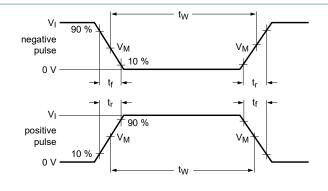
Fig. 6. The data input (A, B) to output (B, A) propagation delay times

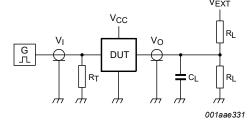


**Table 14. Measurement points** 

Supply voltage	Input [1]	Output [2]						
V <sub>CC(A)</sub> , V <sub>CC(B)</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>				
1.2 V to 1.6 V	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.1 V	V <sub>OH</sub> - 0.1 V				
1.65 V to 2.7 V	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V				
3.0 V to 5.5 V	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V				

- [1]  $V_{CCI}$  is the supply voltage associated with the data input port.
- [2] V<sub>CCO</sub> is the supply voltage associated with the output port.





Test data is given in Table 15.

 $R_L$  = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance.

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig. 8. Test circuit for measuring switching times

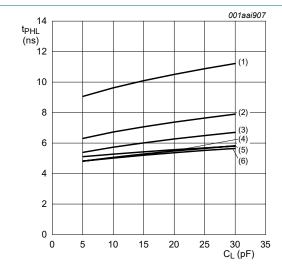
#### Table 15. Test data

Supply voltage	Input		Load		V <sub>EXT</sub>				
V <sub>CC(A)</sub> , V <sub>CC(B)</sub>	V <sub>1</sub> [1] Δt/ΔV [2]		C <sub>L</sub>	R <sub>L</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> [3]		
1.2 V to 5.5 V	V <sub>CCI</sub>	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V <sub>CCO</sub>		

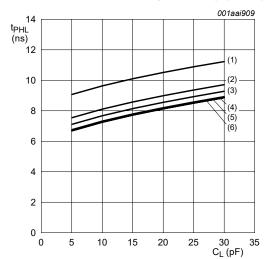
- [1] V<sub>CCI</sub> is the supply voltage associated with the data input port.
- [2] dV/dt ≥ 1.0 V/ns.
- [3] V<sub>CCO</sub> is the supply voltage associated with the output port.

**Product data sheet** 

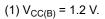
# 12. Typical propagation delay characteristics



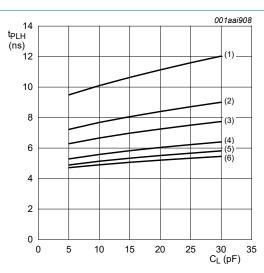
a. HIGH to LOW propagation delay (A to B)



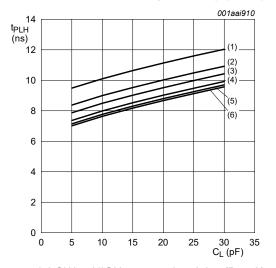
c. HIGH to LOW propagation delay (B to A)



<sup>(2)</sup>  $V_{CC(B)} = 1.5 \text{ V}.$ 



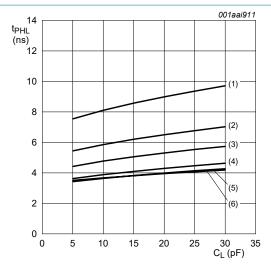
b. LOW to HIGH propagation delay (A to B)



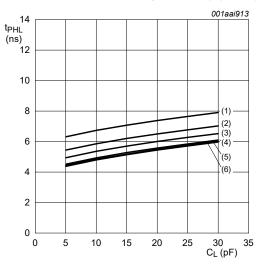
d. LOW to HIGH propagation delay (B to A)

Typical propagation delay versus load capacitance;  $T_{amb}$  = 25 °C;  $V_{CC(A)}$  = 1.2 V

<sup>(3)</sup>  $V_{CC(B)} = 1.8 \text{ V}.$ (4)  $V_{CC(B)} = 2.5 \text{ V}.$ (5)  $V_{CC(B)} = 3.3 \text{ V}.$ (6)  $V_{CC(B)} = 5.0 \text{ V}.$ 



a. HIGH to LOW propagation delay (A to B)

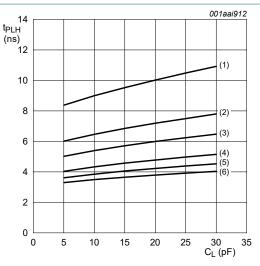


c. HIGH to LOW propagation delay (B to A)

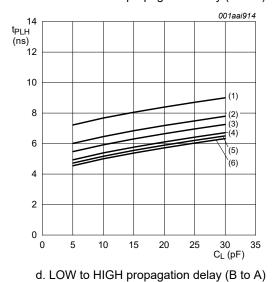
- (1)  $V_{CC(B)} = 1.2 \text{ V}.$
- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$ (4)  $V_{CC(B)} = 2.5 \text{ V}.$ (5)  $V_{CC(B)} = 3.3 \text{ V}.$

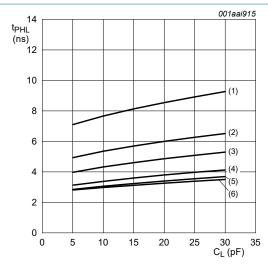
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

Fig. 10. Typical propagation delay versus load capacitance;  $T_{amb}$  = 25 °C;  $V_{CC(A)}$  = 1.5 V

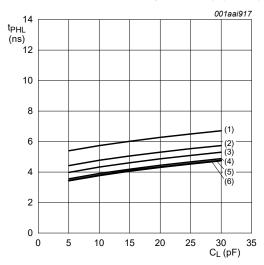


b. LOW to HIGH propagation delay (A to B)





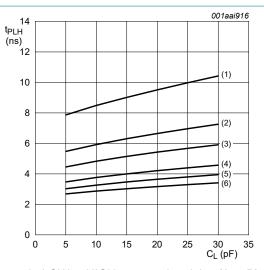
a. HIGH to LOW propagation delay (A to B)



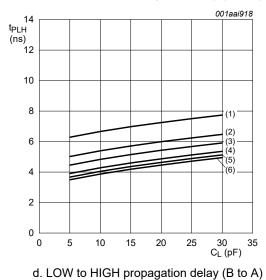
c. HIGH to LOW propagation delay (B to A)

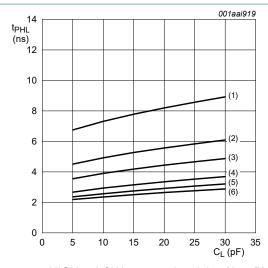
- (1)  $V_{CC(B)} = 1.2 \text{ V}.$
- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$ (4)  $V_{CC(B)} = 2.5 \text{ V}.$ (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

Fig. 11. Typical propagation delay versus load capacitance;  $T_{amb}$  = 25 °C;  $V_{CC(A)}$  = 1.8 V

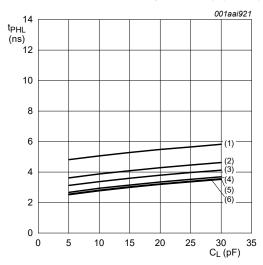


b. LOW to HIGH propagation delay (A to B)





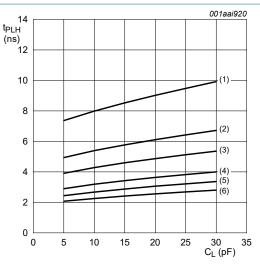
a. HIGH to LOW propagation delay (A to B)



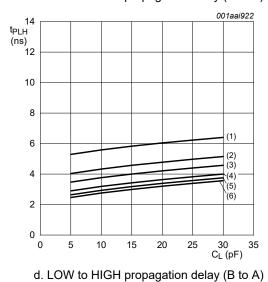
c. HIGH to LOW propagation delay (B to A)

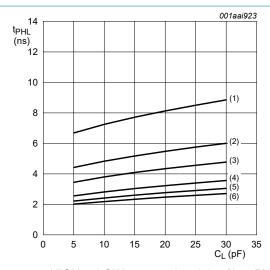
- (1)  $V_{CC(B)} = 1.2 \text{ V}.$
- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$ (4)  $V_{CC(B)} = 2.5 \text{ V}.$ (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

Fig. 12. Typical propagation delay versus load capacitance;  $T_{amb}$  = 25 °C;  $V_{CC(A)}$  = 2.5 V

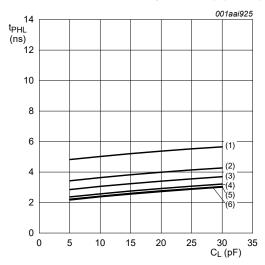


b. LOW to HIGH propagation delay (A to B)





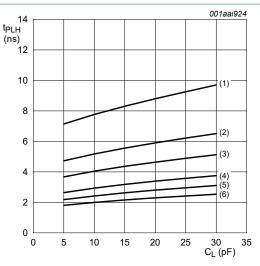
a. HIGH to LOW propagation delay (A to B)



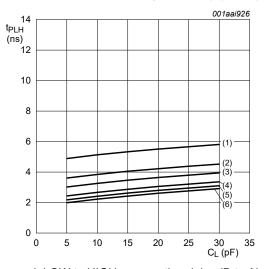
c. HIGH to LOW propagation delay (B to A)

- (1)  $V_{CC(B)} = 1.2 \text{ V}.$
- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$ (4)  $V_{CC(B)} = 2.5 \text{ V}.$ (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

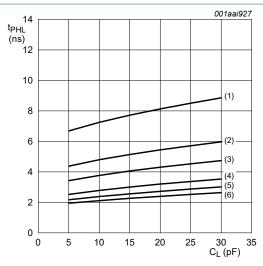
Fig. 13. Typical propagation delay versus load capacitance;  $T_{amb}$  = 25 °C;  $V_{CC(A)}$  = 3.3 V



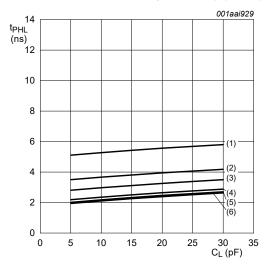
b. LOW to HIGH propagation delay (A to B)



d. LOW to HIGH propagation delay (B to A)



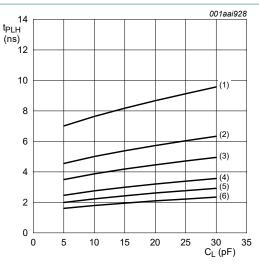
a. HIGH to LOW propagation delay (A to B)



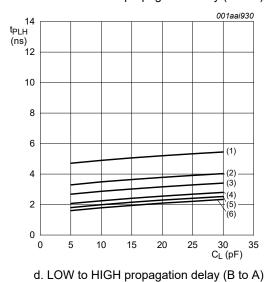
c. HIGH to LOW propagation delay (B to A)

- (1)  $V_{CC(B)} = 1.2 \text{ V}.$
- (2)  $V_{CC(B)} = 1.5 \text{ V}.$
- (3)  $V_{CC(B)} = 1.8 \text{ V}.$ (4)  $V_{CC(B)} = 2.5 \text{ V}.$ (5)  $V_{CC(B)} = 3.3 \text{ V}.$
- (6)  $V_{CC(B)} = 5.0 \text{ V}.$

Fig. 14. Typical propagation delay versus load capacitance;  $T_{amb}$  = 25 °C;  $V_{CC(A)}$  = 5.0 V



b. LOW to HIGH propagation delay (A to B)



# 13. Application information

### 13.1. Unidirectional logic level-shifting application

The circuit given in Fig. 15 is an example of the 74LVC2T45; 74LVCH2T45 being used in a unidirectional logic level-shifting application.

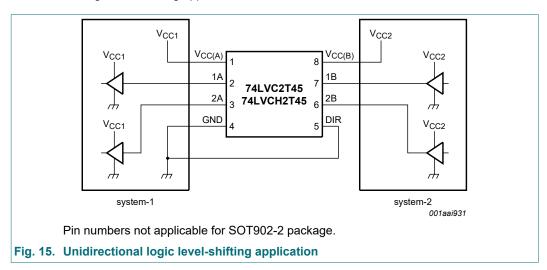
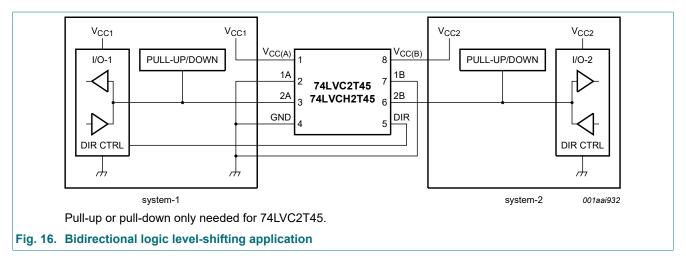


Table 16. Description of unidirectional logic level-shifting application

Pin	Name	Function	Description
1	V <sub>CC(A)</sub>	V <sub>CC1</sub>	supply voltage of system-1 (1.2 V to 5.5 V)
2	1A	OUT	output level depends on V <sub>CC1</sub> voltage
3	2A	OUT	output level depends on V <sub>CC1</sub> voltage
4	GND	GND	device GND
5	DIR	DIR	the GND (LOW level) determines B port to A port direction
6	2B	IN	input threshold value depends on V <sub>CC2</sub> voltage
7	1B	IN	input threshold value depends on V <sub>CC2</sub> voltage
8	V <sub>CC(B)</sub>	V <sub>CC2</sub>	supply voltage of system-2 (1.2 V to 5.5 V)

### 13.2. Bidirectional logic level-shifting application

<u>Fig. 16</u> shows the 74LVC2T45; 74LVCH2T45 being used in a bidirectional logic level-shifting application. Since the device does not have an output enable pin, the system designer should take precautions to avoid bus contention between system-1 and system-2 when changing directions.



<u>Table 17</u> gives a sequence that will illustrate data transmission from system-1 to system-2 and then from system-2 to system-1.

#### Table 17. Description of bidirectional logic level-shifting application

H = HIGH voltage level;

 $L = LOW \ voltage \ level;$ 

Z = high-impedance OFF-state.

State	DIR CTRL	I/O-1	I/O-2	Description
1	Н	output	input	system-1 data to system-2
2	Н	Z	Z	system-2 is getting ready to send data to system-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on bus hold
3	L	Z	Z	DIR bit is set LOW. I/O-1 and I/O-2 still are disabled. The bus-line state depends on bus hold
4	L	input	output	system-2 data to system-1

#### 13.3. Power-up considerations

The device is designed such that no special power-up sequence is required other than GND being applied first.

Table 18. Typicaltotal supply current  $(I_{CC(A)} + I_{CC(B)})$ 

V <sub>CC(A)</sub>	V <sub>CC(B)</sub>	V <sub>CC(B)</sub>									
	0 V	1.8 V	2.5 V	3.3 V	5.0 V						
0 V	0	< 1	< 1	< 1	< 1	μΑ					
1.8 V	< 1	< 2	< 2	< 2	2	μΑ					
2.5 V	< 1	< 2	< 2	< 2	< 2	μΑ					
3.3 V	< 1	< 2	< 2	< 2	< 2	μΑ					
5.0 V	< 1	2	< 2	< 2	< 2	μΑ					

Product data sheet

#### 13.4. Enable times

Calculate the enable times for the 74LVC2T45; 74LVCH2T45 using the following formulas:

- $t_{PZH}$  (DIR to A) =  $t_{PLZ}$  (DIR to B) +  $t_{PLH}$  (B to A)
- $t_{PZL}$  (DIR to A) =  $t_{PHZ}$  (DIR to B) +  $t_{PHL}$  (B to A)
- t<sub>PZH</sub> (DIR to B) = t<sub>PLZ</sub> (DIR to A) + t<sub>PLH</sub> (A to B)
- $t_{PZL}$  (DIR to B) =  $t_{PHZ}$  (DIR to A) +  $t_{PHL}$  (A to B)

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the 74LVC2T45; 74LVCH2T45 initially is transmitting from A to B, then the DIR bit is switched, the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.

# 14. Package outline

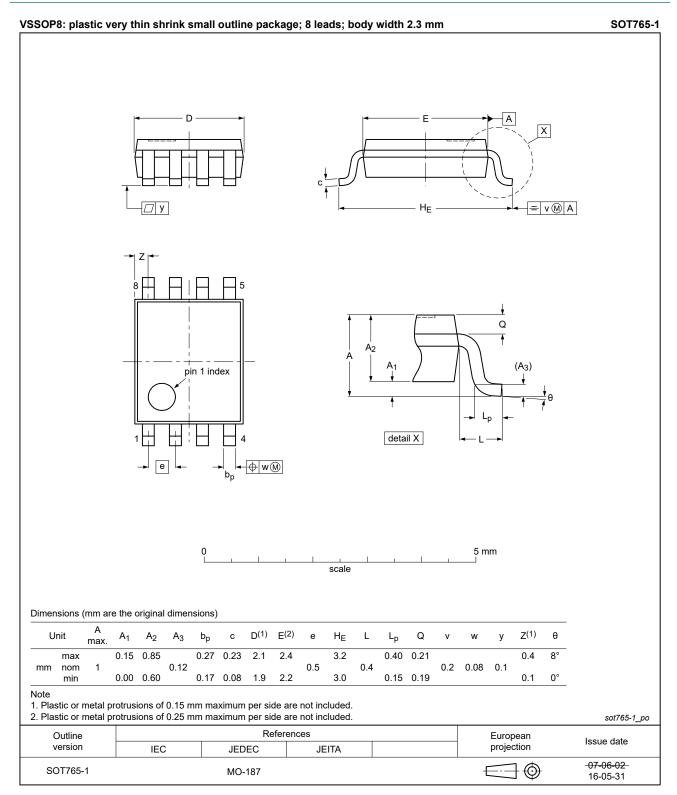


Fig. 17. Package outline SOT765-1 (VSSOP8)

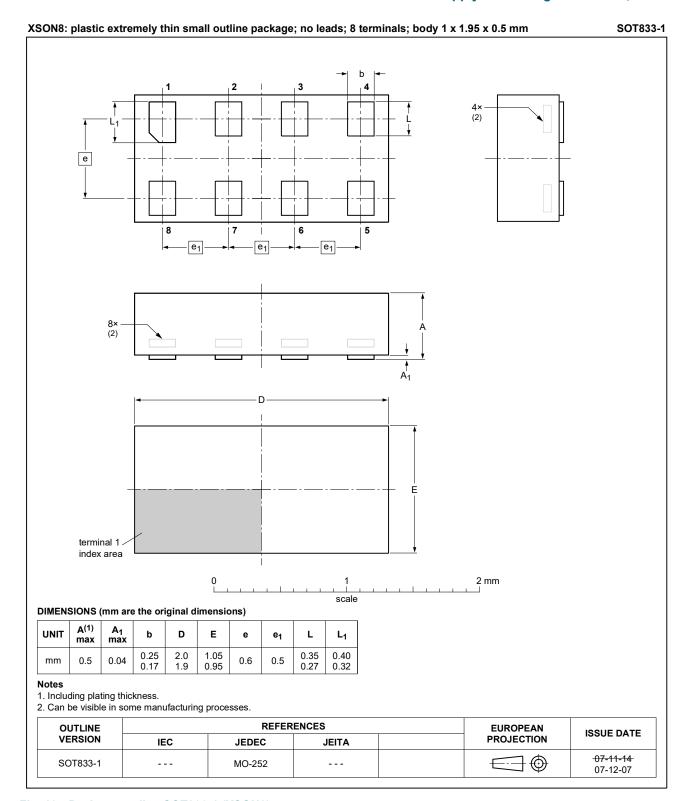


Fig. 18. Package outline SOT833-1 (XSON8)

**Product data sheet** 

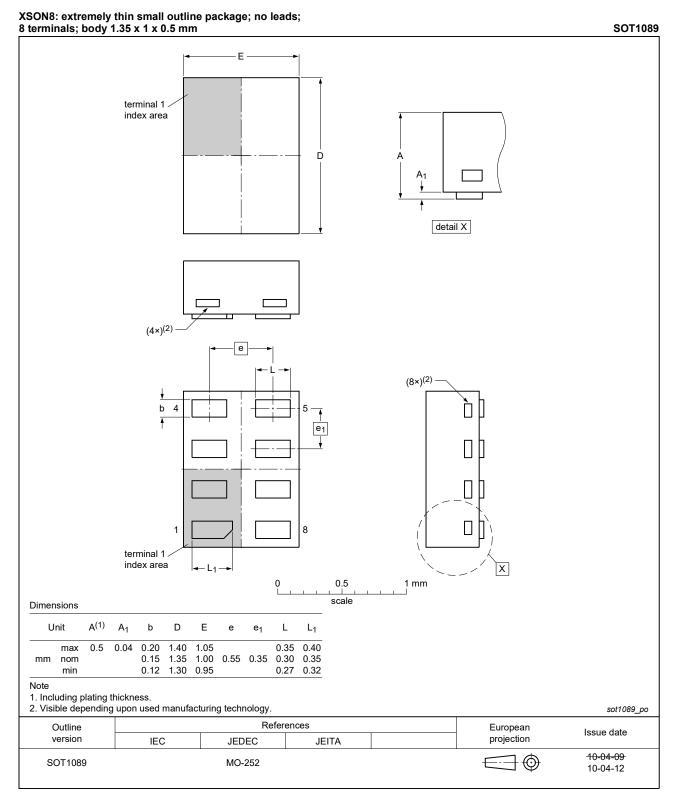


Fig. 19. Package outline SOT1089 (XSON8)

**Product data sheet** 

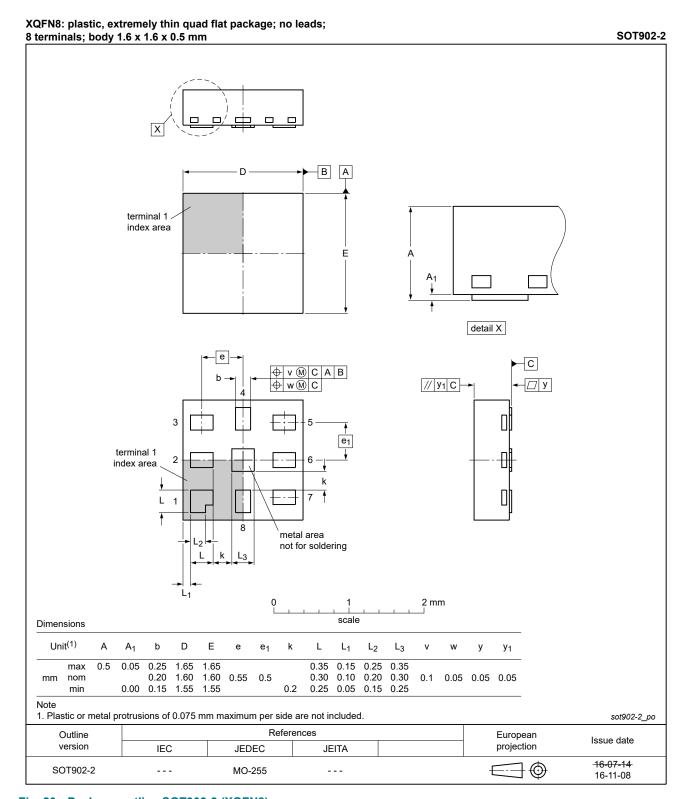


Fig. 20. Package outline SOT902-2 (XQFN8)

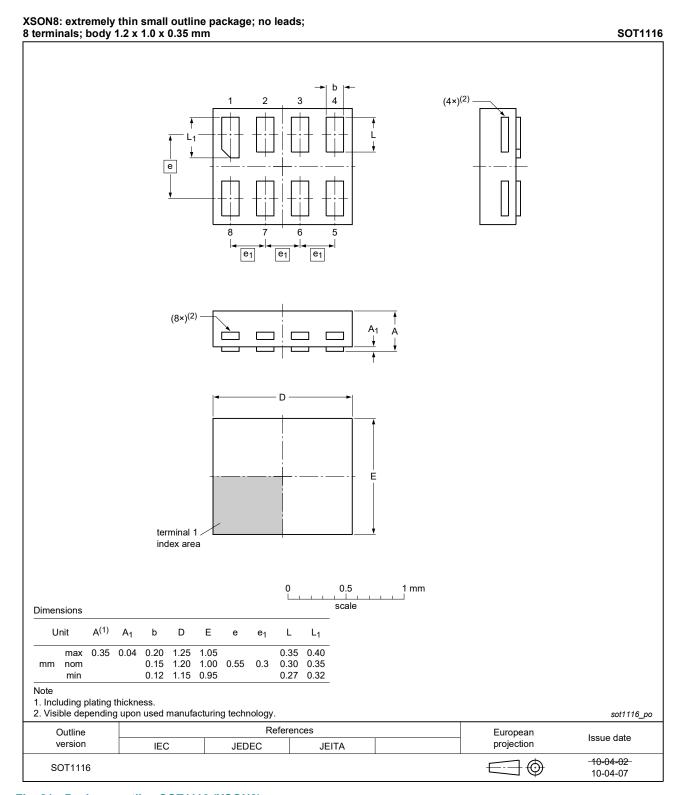


Fig. 21. Package outline SOT1116 (XSON8)

**Product data sheet** 

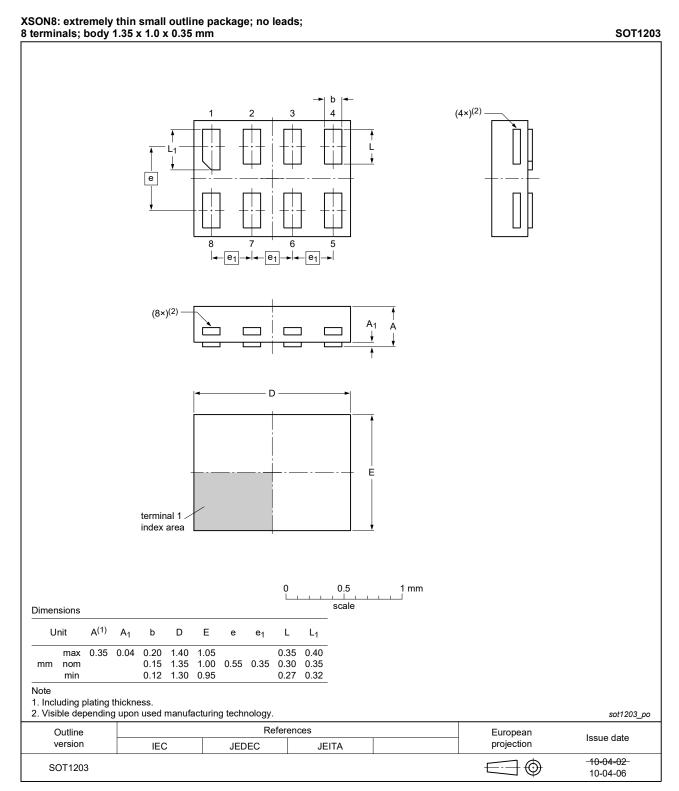


Fig. 22. Package outline SOT1203 (XSON8)

**Product data sheet** 

## 15. Abbreviations

#### **Table 19. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

## 16. Revision history

### Table 20. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LVC_LVCH2T45 v.10	20210511	Product data sheet	-	74LVC_LVCH2T45 v.9		
Modifications:	Type number 74LVCH2T45GM (SOT902-2 / XQFN8) removed.					
	• <u>Section 8</u> : Derating values for P <sub>tot</sub> total power dissipation updated.					
74LVC_LVCH2T45 v.9	20180813	Product data sheet	-	74LVC_LVCH2T45 v.8		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type numbers 74LVC2T45GD and 74LVCH2T45GD (SOT996-2) removed.</li> <li>Fig. 17: Package outline drawing (SOT765-1) modified.</li> </ul>					
74LVC_LVCH2T45 v.8	20130329	Product data sheet	-	74LVC_LVCH2T45 v.7		
Modifications:	For type numbers 74LVC2T45GD and 74LVCH2T45GD XSON8U has changed to XSON8.					
74LVC_LVCH2T45 v.7	20120619	Product data sheet	-	74LVC_LVCH2T45 v.6		
Modifications:	<ul> <li>For type numbers 74LVC2T45GM and 74LVCH2T45GM the SOT code has changed to SOT902-2.</li> </ul>					
74LVC_LVCH2T45 v.6	20111209	Product data sheet	-	74LVC_LVCH2T45 v.5		
Modifications:	Legal pages updated.					
74LVC_LVCH2T45 v.5	20110927	Product data sheet	-	74LVC_LVCH2T45 v.4		
74LVC_LVCH2T45 v.4	20100820	Product data sheet	-	74LVC_LVCH2T45 v.3		
74LVC_LVCH2T45 v.3	20100119	Product data sheet	-	74LVC_LVCH2T45 v.2		
74LVC_LVCH2T45 v.2	20090205	Product data sheet	-	74LVC_LVCH2T45 v.1		
74LVC_LVCH2T45 v.1	20081118	Product data sheet	-	-		

**Product data sheet** 

## 17. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

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## **Contents**

1. General description	1
2. Features and benefits	1
3. Ordering information	2
4. Marking	2
5. Functional diagram	3
6. Pinning information	3
6.1. Pinning	3
6.2. Pin description	4
7. Functional description	4
8. Limiting values	5
9. Recommended operating conditions	5
10. Static characteristics	6
11. Dynamic characteristics	9
11.1. Waveforms and test circuit	15
12. Typical propagation delay characteristics	17
13. Application information	23
13.1. Unidirectional logic level-shifting application	23
13.2. Bidirectional logic level-shifting application	24
13.3. Power-up considerations	24
13.4. Enable times	25
14. Package outline	26
15. Abbreviations	32
16. Revision history	32
17. Legal information	33

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